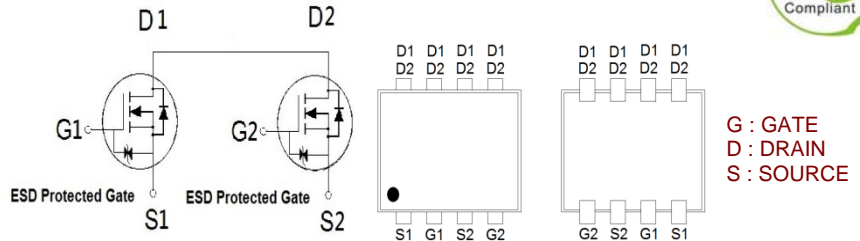




**PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
20V	11.8mΩ	10.5A



**ABSOLUTE MAXIMUM RATINGS ( $T_A = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		$V_{DS}$	20	V
Gate-Source Voltage		$V_{GS}$	±10	V
Continuous Drain Current <sup>2</sup>	$T_A = 25\text{ }^\circ\text{C}$	$I_D$	10.5	A
	$T_A = 70\text{ }^\circ\text{C}$		8.4	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	28	
Avalanche Current		$I_{AS}$	22	
Avalanche Energy	$L = 0.1\text{mH}$	$E_{AS}$	24	mJ
Power Dissipation <sup>3</sup>	$T_A = 25\text{ }^\circ\text{C}$	$P_D$	2.1	W
	$T_A = 70\text{ }^\circ\text{C}$		1.3	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE		SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Ambient	$t \leq 10\text{s}$	$R_{\theta JA}$		58	°C / W
Junction-to-Ambient	Steady-State	$R_{\theta JA}$		73	

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Package limitation current is 7A.

<sup>3</sup>The Power dissipation is based on  $R_{\theta JA} t \leq 10\text{s}$  value.

**ELECTRICAL CHARACTERISTICS ( $T_j = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	20			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.35	0.7	1	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{V}, V_{GS} = \pm 8\text{V}$			±30	uA

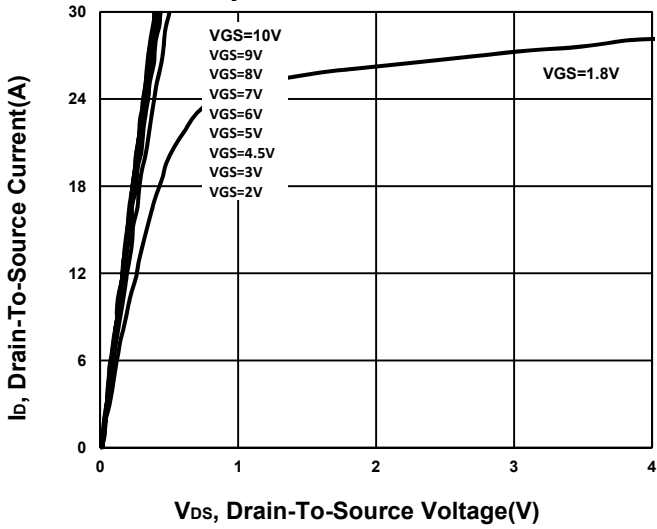
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 16V, V_{GS} = 0V$			1	$\mu A$
		$V_{DS} = 10V, V_{GS} = 0V, T_J = 70^\circ C$			10	
Drain-Source On-State Resistance <sup>1</sup>	$R_{DS(ON)}$	$V_{GS} = 2.5V, I_D = 3A$	8.5	13	20	$m\Omega$
		$V_{GS} = 3.1V, I_D = 3A$	7.8	11.5	15.3	
		$V_{GS} = 3.8V, I_D = 3A$	7.2	10.6	12.9	
		$V_{GS} = 4.5V, I_D = 3A$	7.1	10	11.8	
Forward Transconductance <sup>1</sup>	$g_{fs}$	$V_{DS} = 5V, I_D = 3A$		40		S
<b>DYNAMIC</b>						
Input Capacitance	$C_{iss}$	$V_{GS} = 0V, V_{DS} = 10V, f = 1MHz$		1133		$pF$
Output Capacitance	$C_{oss}$			214		
Reverse Transfer Capacitance	$C_{rss}$			168		
Gate Resistance	$R_g$	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$		1.5		$\Omega$
Total Gate Charge <sup>2</sup>	$Q_g$	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 3A$		17.4		$nC$
Gate-Source Charge <sup>2</sup>	$Q_{gs}$			1.1		
Gate-Drain Charge <sup>2</sup>	$Q_{gd}$			5.1		
Turn-On Delay Time <sup>2</sup>	$t_{d(on)}$	$V_{DS} = 10V, I_D \cong 3A, V_{GS} = 4.5V, R_G = 6\ \Omega$		24		$nS$
Rise Time <sup>2</sup>	$t_r$			32		
Turn-Off Delay Time <sup>2</sup>	$t_{d(off)}$			66		
Fall Time <sup>2</sup>	$t_f$			35		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Continuous Current	$I_S$			1.7		A
Forward Voltage <sup>1</sup>	$V_{SD}$	$I_F = 3A, V_{GS} = 0V$		1.2		V
Reverse Recovery Time	$t_{rr}$	$I_F = 3A, di_F/dt = 100A / \mu S$		14		nS
Reverse Recovery Charge	$Q_{rr}$			5.4		nC

<sup>1</sup>Pulse test : Pulse Width  $\leq 300\ \mu sec$ , Duty Cycle  $\leq 2\%$ .

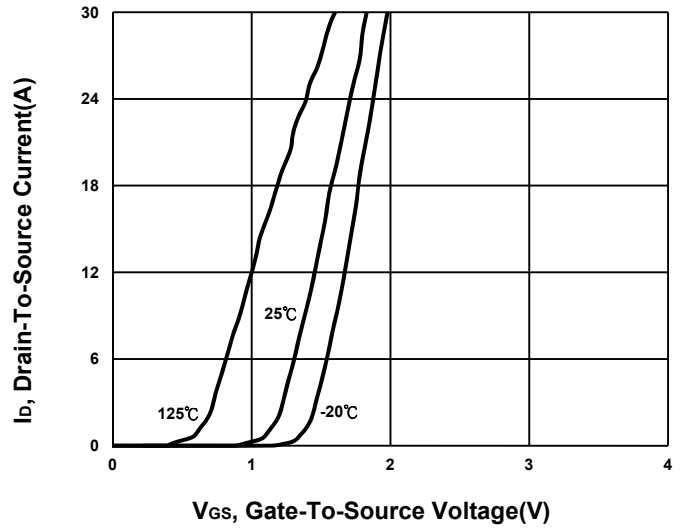
<sup>2</sup>Independent of operating temperature.

<sup>3</sup>Pulse width limited by maximum junction temperature.

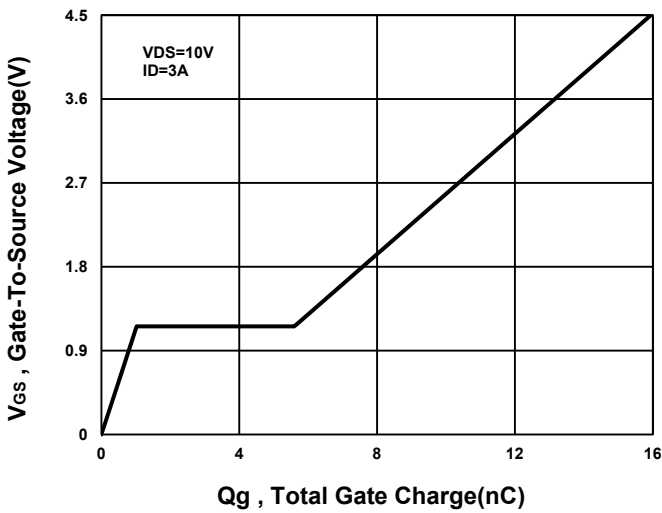
**Output Characteristics**



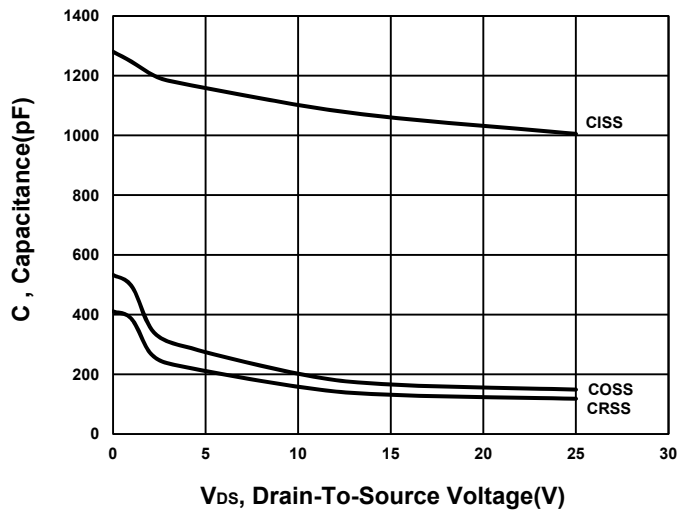
**Transfer Characteristics**



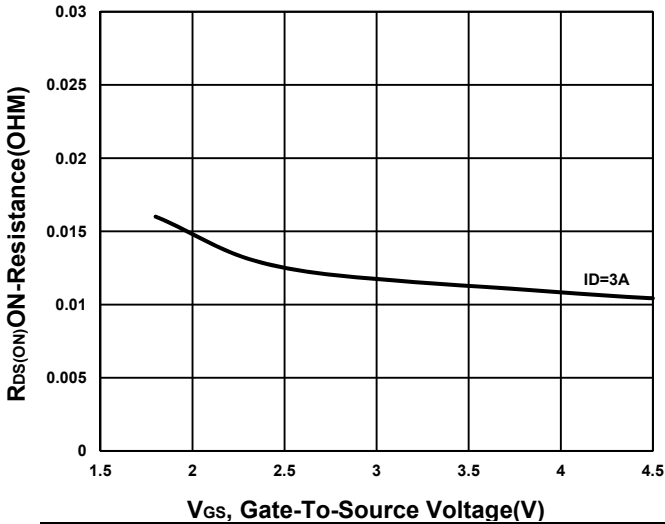
**Gate charge Characteristics**



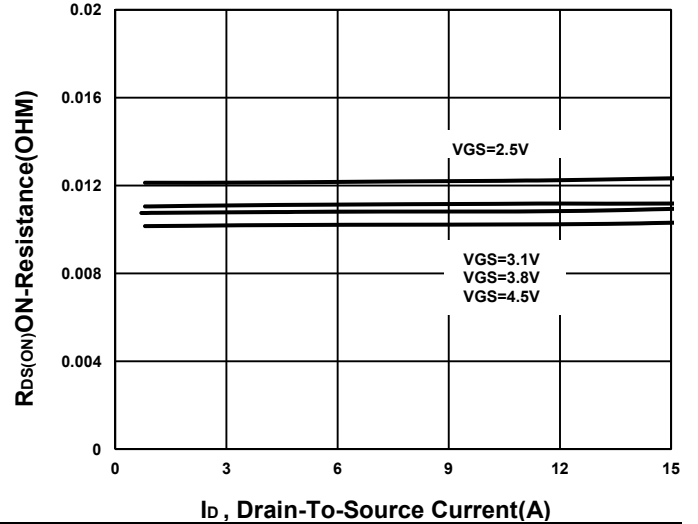
**Capacitance Characteristic**



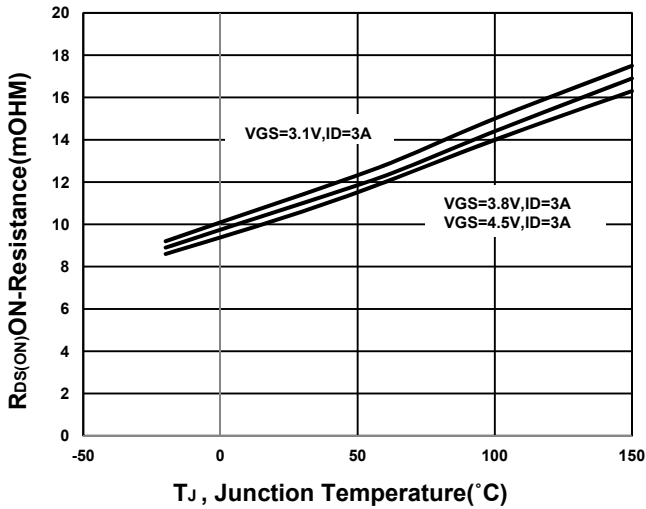
**On-Resistance VS Gate-To-Source**



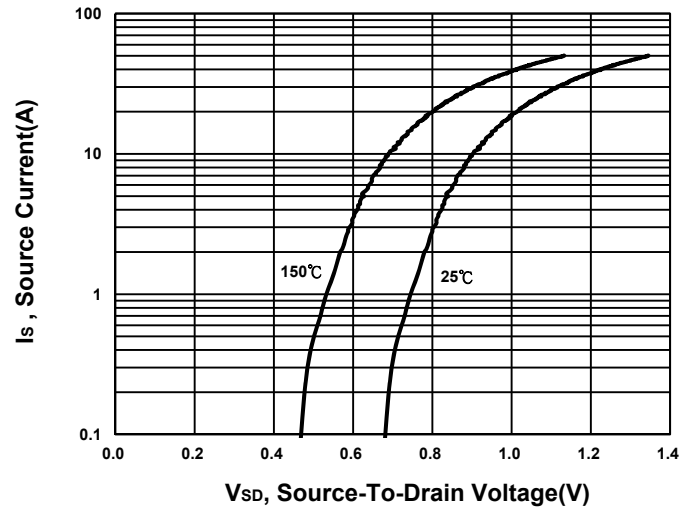
**On-Resistance VS Drain Current**



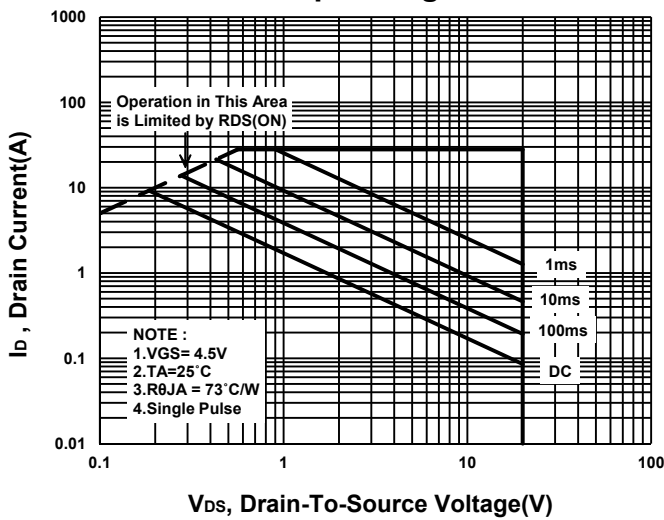
**On-Resistance VS Temperature**



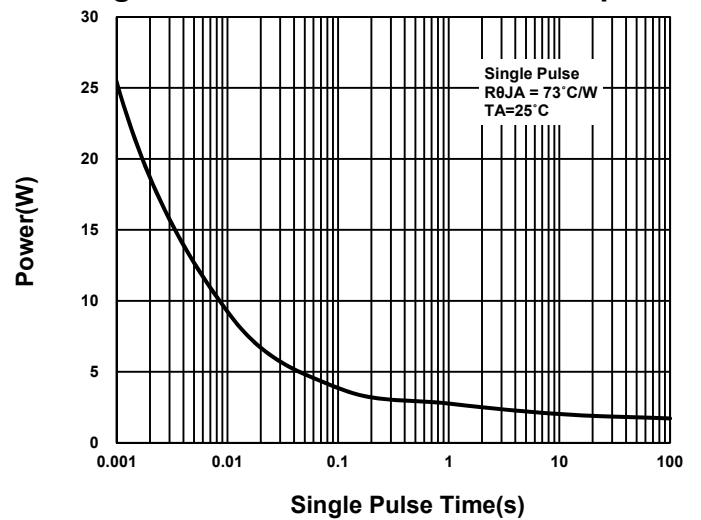
**Source-Drain Diode Forward Voltage**



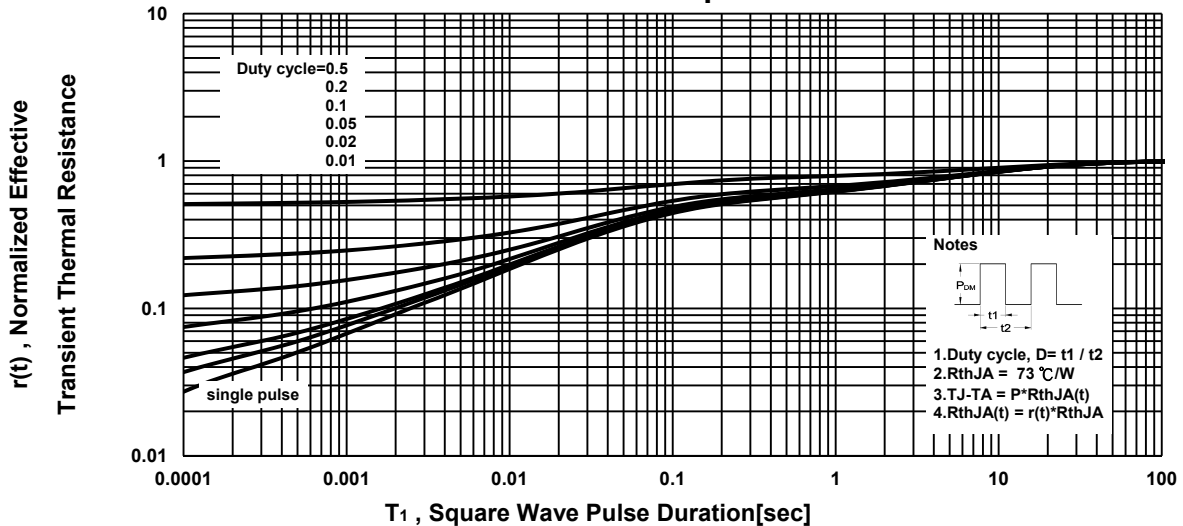
**Safe Operating Area**



**Single Pulse Maximum Power Dissipation**



**Transient Thermal Response Curve**



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